

October 1987 Revised January 1999

# CD4013BC Dual D-Type Flip-Flop

#### **General Description**

The CD4013B dual D-type flip-flop is a monolithic complementary MOS (CMOS) integrated circuit constructed with N- and P-channel enhancement mode transistors. Each flip-flop has independent data, set, reset, and clock inputs and "Q" and "Q" outputs. These devices can be used for shift register applications, and by connecting "Q" output to the data input, for counter and toggle applications. The logic level present at the "D" input is transferred to the Q output during the positive-going transition of the clock pulse. Setting or resetting is independent of the clock and is accomplished by a high level on the set or reset line respectively.

#### **Features**

Wide supply voltage range: 3.0V to 15V
High noise immunity: 0.45 V<sub>DD</sub> (typ.)
Low power TTL: fan out of 2 driving 74L compatibility: or 1 driving 74LS

#### **Applications**

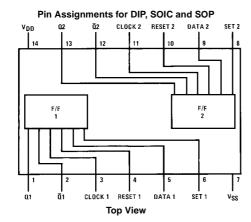
- Automotive
- · Data terminals
- Instrumentation
- Medical electronics
- Alarm system
- Industrial electronics
- Remote metering
- Computers

## **Ordering Code:**

Order Number	Package Number	Package Description
CD4013BCM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
CD4013BCSJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
CD4013BCN	N14A	14-Lead Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code

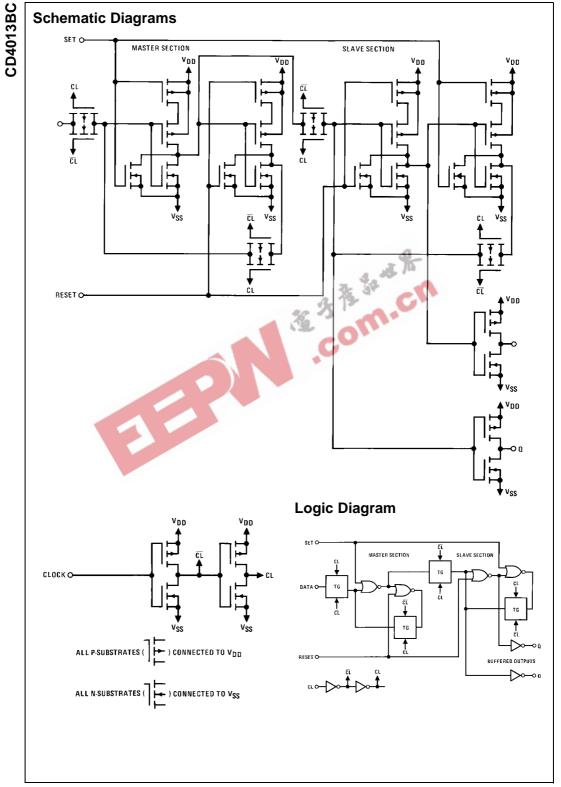
## **Connection Diagram**



#### **Truth Table**

CL (Note 1)	D	R	s	Q	Q
\	0	0	0	0	1
~	1	0	0	1	0
7	х	0	0	Q	Q
х	х	1	0	0	1
х	х	0	1	1	0
х	х	1	1	1	1

No Change x = Don't Care Case **Note 1:** Level Change



## Absolute Maximum Ratings(Note 2)

(Note 3)

DC Supply Voltage (V<sub>DD</sub>)  $-0.5 \text{ V}_{DC} \text{ to } +18 \text{ V}_{DC}$  Input Voltage (V<sub>IN</sub>)  $-0.5 \text{ V}_{DC} \text{ to V}_{DD} +0.5 \text{ V}_{DC}$  Storage Temperature Range (T<sub>S</sub>)  $-65^{\circ}\text{C to } +150^{\circ}\text{C}$ 

Power Dissipation (P<sub>D</sub>)

Dual-In-Line 700 mW Small Outline 500 mW

Lead Temperature  $(T_L)$ 

(Soldering, 10 seconds) 260°C

# **Recommended Operating Conditions** (Note 3)

DC Supply Voltage ( $V_{DD}$ ) +3  $V_{DC}$  to +15  $V_{DC}$  Input Voltage ( $V_{IN}$ ) 0  $V_{DC}$  to  $V_{DD}$   $V_{DC}$  Operating Temperature Range ( $T_A$ ) -40°C to +85°C

Note 2: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed, they are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.

Note 3:  $V_{SS} = 0V$  unless otherwise specified.

## DC Electrical Characteristics (Note 3)

Symbol	Parameter	Conditions	–40°C		+25°C			+85°C		Units
Cynnbon	i arameter	Conditions	Min	Max	Min	Тур	Max	Min	Max	Oills
I <sub>DD</sub>	Quiescent Device	$V_{DD} = 5V$ , $V_{IN} = V_{DD}$ or $V_{SS}$		4.0			4.0		30	μΑ
	Current	$V_{DD} = 10V$ , $V_{IN} = V_{DD}$ or $V_{SS}$		8.0			8.0		60	μΑ
		$V_{DD} = 15V$ , $V_{IN} = V_{DD}$ or $V_{SS}$		16.0			16.0		120	μΑ
V <sub>OL</sub>	LOW Level	I <sub>O</sub>   < 1.0 μA				16	/10			
	Output Voltage	$V_{DD} = 5V$		0.05	7 %	3-	0.05		0.05	V
		$V_{DD} = 10V$		0.05	後。		0.05		0.05	V
		V <sub>DD</sub> = 15V	40	0.05	1		0.05		0.05	V
V <sub>OH</sub>	HIGH Level	I <sub>O</sub>   < 1.0 μA	13	-		7 10				
	Output Voltage	$V_{DD} = 5V$	4.95	40	4.95			4.95		V
		V <sub>DD</sub> = 10V	9.95		9.95			9.95		V
		V <sub>DD</sub> = 15V	14.95		14.95			14.95		V
V <sub>IL</sub>	LOW Level	l <sub>O</sub>   < 1.0 μA								
	Input Voltage	$V_{DD} = 5V, V_{O} = 0.5V \text{ or } 4.5V$	_	1.5			1.5		1.5	V
		$V_{DD} = 10V, V_{O} = 1.0V \text{ or } 9.0V$		3.0			3.0		3.0	V
		$V_{DD} = 15V$ , $V_{O} = 1.5V$ or 13.5V		4.0			4.0		4.0	V
V <sub>IH</sub>	HIGH Level	I <sub>O</sub>   < 1.0 μΑ								
	Input Voltage	$V_{DD} = 5V$ , $V_{O} = 0.5V$ or 4.5V	3.5		3.5			3.5		V
		$V_{DD} = 10V, V_{O} = 1.0V \text{ or } 9.0V$	7.0		7.0			7.0		V
		$V_{DD} = 15V, V_{O} = 1.5V \text{ or } 13.5V$	11.0		11.0			11.0		V
I <sub>OL</sub>	LOW Level Output	$V_{DD} = 5V, V_{O} = 0.4V$	0.52		0.44	0.88		0.36		mA
	Current (Note 4)	$V_{DD} = 10V, V_{O} = 0.5V$	1.3		1.1	2.25		0.9		mA
		$V_{DD} = 15V, V_{O} = 1.5V$	3.6		3.0	8.8		2.4		mA
I <sub>OH</sub>	HIGH Level Output	$V_{DD} = 5V, V_{O} = 4.6V$	-0.52		-0.44	-0.88		-0.36		mA
	Current (Note 4)	$V_{DD} = 10V, V_{O} = 9.5V$	-1.3		-1.1	-2.25		-0.9		mA
		$V_{DD} = 15V, V_{O} = 13.5V$	-3.6		-3.0	-8.8		-2.4		mA
I <sub>IN</sub>	Input Current	$V_{DD} = 15V, V_{IN} = 0V$		-0.3		-10 <sup>-5</sup>	-0.3		-1.0	μΑ
		$V_{DD} = 15V, V_{IN} = 15V$		0.3		10 <sup>-5</sup>	0.3		1.0	μΑ

Note 4: I<sub>OH</sub> and I<sub>OL</sub> are measured one output at a time.

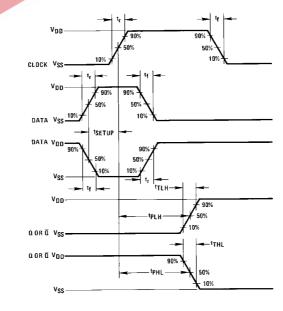
# AC Electrical Characteristics (Note 5)

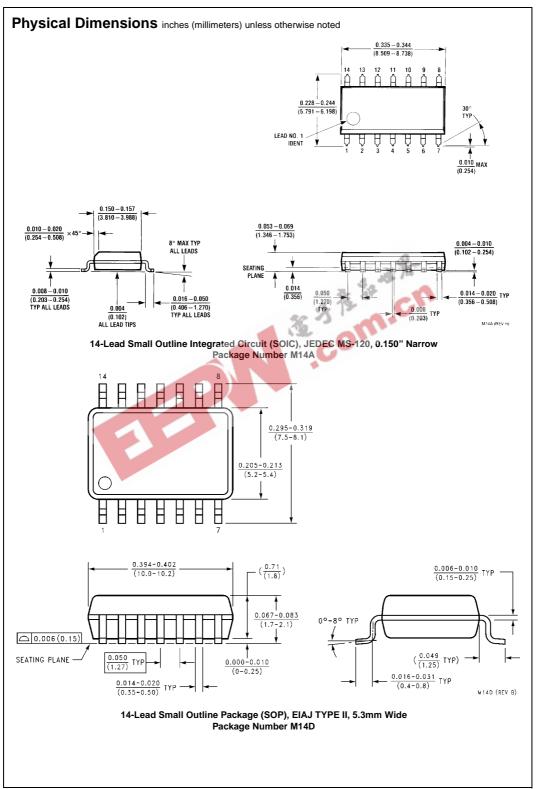
 $\rm T_A = 25^{\circ}C, \ C_L = 50 \ pF, \ R_L = 200k, \ unless \ otherwise \ noted$ 

Symbol	Parameter	Conditions	Min	Тур	Max	Units
CLOCK OPERATI	ION					
t <sub>PHL</sub> , t <sub>PLH</sub>	Propagation Delay Time	$V_{DD} = 5V$		200	350	ns
		$V_{DD} = 10V$		80	160	ns
		$V_{DD} = 15V$		65	120	ns
t <sub>THL</sub> , t <sub>TLH</sub>	Transition Time	$V_{DD} = 5V$		100	200	ns
		$V_{DD} = 10V$		50	100	ns
		$V_{DD} = 15V$		40	80	ns
t <sub>WL</sub> , t <sub>WH</sub>	Minimum Clock	$V_{DD} = 5V$		100	200	ns
	Pulse Width	$V_{DD} = 10V$		40	80	ns
		$V_{DD} = 15V$		32	65	ns
t <sub>RCL</sub> , t <sub>FCL</sub>	Maximum Clock Rise and	$V_{DD} = 5V$			15	μs
	Fall Time	$V_{DD} = 10V$			10	μs
		$V_{DD} = 15V$			5	μs
tsu	Minimum Set-Up Time	$V_{DD} = 5V$		20	40	ns
		$V_{DD} = 10V$		<b>1</b> 5	30	ns
		$V_{DD} = 15V$	.3	12	25	ns
f <sub>CL</sub>	Maximum Clock	$V_{DD} = 5V$	2.5	5		MHz
	Frequency	$V_{DD} = 10V$	6.2	12.5		MHz
		V <sub>DD</sub> = 15V	7.6	<b>1</b> 5.5		MHz
SET AND RESET	OPERATION	4 36	-40			
PHL(R),	Propagation Delay Time	$V_{DD} = 5V$	35.	150	300	ns
PLH(S)		V <sub>DD</sub> = 10V		65	130	ns
		V <sub>DD</sub> = 15V		45	90	ns
WH(R),	Minimum Set and	$V_{DD} = 5V$		90	180	ns
WH(S)	Reset Pulse Width	V <sub>DD</sub> = 10V		40	80	ns
		V <sub>DD</sub> = 15V		25	50	ns
C <sub>IN</sub>	Average Input Capacitance	Any Input		5	7.5	pF

Note 5: AC Parameters are guaranteed by DC correlated testing.

# **Switching Time Waveforms**





#### Physical Dimensions inches (millimeters) unless otherwise noted (Continued) $\frac{0.740 - 0.770}{(18.80 - 19.56)}$ (2.286) 14 13 12 14 13 12 11 10 9 8 $0.250 \pm 0.010$ (6.350 ± 0.254) PIN NO. 1 IDENT PIN NO. 1 IDENT 1 2 3 4 5 6 7 1 2 3 $\frac{0.092}{(2.337)}$ DIA $\frac{0.030}{(0.762)}$ MAX DEPTH OPTION 1 OPTION 02 $\frac{0.135 \pm 0.005}{(3.429 \pm 0.127)}$ 0.300 - 0.320(7.620 - 8.128) 0.065 0.145 - 0.2000.060 4° TYP TYP (1.524) (3.683 - 5.080)OPTIONAL \* $\frac{0.008 - 0.016}{(0.203 - 0.406)} \text{ TYP}$ 0.020 $\frac{0.125 - 0.150}{(3.175 - 3.810)}$ 0.280 $(1.905 \pm 0.381)$ (7.112)-MIN $\frac{0.014-0.023}{(0.356-0.584)} \text{ TYP}$ 0.100 ± 0.010 (2.540 ± 0.254)

14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N14A

 $\frac{0.050 \pm 0.010}{(1.270 - 0.254)} \text{ TYF}$ 

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N14A (REV F)

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